

BAY AREA AIR QUALITY MANAGEMENT DISTRICT

939 Ellis Street . . . San Francisco, CA 94109. . . (415) 749-4990

**DATA FORM F
Semiconductor Fabrication Area**

New Modified Retro
(for office use only)

Vertical rectangular box for stamp or marking.

Form F is for the following equipment used in the manufacture of semiconductors or related solid state devices: Solvent Stations, Wet Chemical Stations, Siliconizing Reactors, Chemical Vapor Deposition, Diffusion Furnaces and Photoresist Lines. One Form F should be completed for all such equipment in each Fabrication Area. SEE PAGE 2 FOR INSTRUCTIONS.

- Company Name _____ Plant No: _____
If Unknown, leave blank)
- Name or Description of Fabrication Area _____
- Effective Date _____ Source No. S-_____
- Equipment Type (Check one or more and complete corresponding parts below):
 Solvent Stations (Part A) Diffusion Furnaces (Part E)
 Wet Chemical Stations (Part B) Photoresist Lines (Part F)
 Siliconizing Reactors (Part C) Exempt Sources (Part G)
 Chemical Vapor Deposition (Part D)
- Typical Use _____ hours/day _____ days/week _____ weeks/year
- Typical % of total annual usage: Dec-Feb _____ % Mar-May _____ % Jun-Aug _____ % Sep-Nov _____ %

Part A - Solvent Stations

- Aggregate Holding Capacity _____ gal Number of solvent station hoods _____
- Do all solvent containing reservoirs, sinks, and containers have covers?
With regard to air pollutant flow, what abatement devices and/or emission points are *immediately* downstream?
- Abatement Devices A _____ A _____ A _____ Emission Points P _____ P _____ P _____

Part B - Wet Chemical Stations

- Aggregate Holding Capacity _____ gal Number of Wet Station Hoods _____
With regard to air pollutant flow, what abatement devices and/or emission points are *immediately* downstream?
- Abatement Devices A _____ A _____ A _____ Emission Points P _____ P _____ P _____

Part C - Siliconizing Reactors

- Number of Reactors _____
With regard to air pollutant flow, what abatement devices and/or emission points are *immediately* downstream?
- Abatement Devices A _____ A _____ A _____ Emission Points P _____ P _____ P _____

Part D - Chemical Vapor Deposition (excluding vacuum and low pressure CVD)

- Number of Chambers _____
With regard to air pollutant flow, what abatement devices and/or emission points are *immediately* downstream?
- Abatement Devices A _____ A _____ A _____ Emission Points P _____ P _____ P _____

Part E - Diffusion, Oxidizing, Alloying and/or Annealing Furnaces

- Number of Chambers _____
With regard to air pollutant flow, what abatement devices and/or emission points are *immediately* downstream?
- Abatement Devices A _____ A _____ A _____ Emission Points P _____ P _____ P _____

Part F - Photoresist

18. Number of Negative: Applicators _____ Developers _____

With regard to air pollutant flow, what abatement devices and/or emission points are *immediately* downstream?

19. Abatement Devices A _____ A _____ A _____ Emission Points P _____ P _____ P _____

20. Number of Positive: Applicators _____ Developers _____

With regard to air pollutant flow, what abatement devices and/or emission points are *immediately* downstream?

21. Abatement Devices A _____ A _____ A _____ Emission Points P _____ P _____ P _____

Part G - Exempt Equipment - Indicate quantities for the following operations

22. Ion implantation chambers _____

23 Vacuum deposition chambers _____

24 Sputtering chambers _____

25. Lapping and polishing machines _____

26. Plasma etching or ashing chambers _____

Person completing this form:	Date:
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Complete and attach Chemical Usage Summary, Page 3 below

INSTRUCTIONS FOR COMPLETING FORM F

- ♦ Complete Data Form P for each Fabrication Area
- ♦ Complete and attach Data Form U for each Fabrication Area
- ♦ See BAAQMD Regulation 3 for equipment definitions

Number	Instructions
2	Name and/or describe the fabrication area. The effective date is either the date each fabrication area will commence operations, if new, or the date of the most recently installed piece of equipment, if currently operating.
4	Check as many parts as are applicable to each fabrication and complete each part.
7,10	Aggregate holding capacity is the total quantity (#7) solvent or (#10) other chemicals normally being held in all sinks. Number of hoods is the total number of ventilating hoods that exhaust the stations.
14	Exclude vacuum and low pressure CVD.
18,20	<i>Note:</i> In multitrack equipment, each separate track counts as one applicator or developer. In integrated equipment, where the applicator and developer are combined in one machine, count each applicator and each developer.

Usage Information

Note usage of each material. Annual throughput, for each material, = usage in pure form + usage as constituent of other mixture.

	Material Code	Annual Usage 1000 gal/yr
Acetone	455	
Butyl Acetate	48	
Chlorofluorocarbons (e.g. freon)	211	
Ethyl Acetate	104	
Ethylene Glycol	131	
Hexamethyldisilazane (HMDS)	508	
Isopropyl Alcohol (IPA)	157	
Methanol	179	
Methyl Ethyl Ketone (MEK)	169	
Methylene Chloride	396	

Photoresist Maskant (negative)	Complete Photoresist Operations table. See following page.
Photoresist Developer (negative)	
Photoresist Maskant (positive)	
Photoresist Developer (positive)	

Trichloroethane (TCA)	294	
Trichloroethylene (TCE)	295	
Toluene	293	
Xylene (Xylol)	307	
Other Organics (precursor)		
Other Organics (nonprecursor)		

Acetic Acid	454	
Ammonium Hydroxide	471	
Anhydrous Ammonia	22	
Aqueous Ammonia	22	
Aqua Regia	507	
Hydrochloric Acid (liq)	149	
Hydrofluoric Acid (HF)	150	
Nitric Acid	191	
Phenol	214	
Sulfuric Acid	146	
Stripper (specify trade name)		
Others		

Annual Usage
liters/yr
(excluding carrier gas)

Arsine	483	
Boron Nitride	483	
Boron Tribromide	483	
Boron Trichloride	483	
Other Boron-containing gases	483	
Phosphine	483	
Silane	483	
Other Dopant gases (specify)	483	

